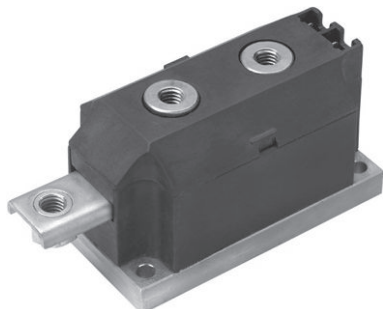


Standard Recovery Diodes, 250 A to 320 A (MAGN-A-PAK Power Modules)



MAGN-A-PAK

FEATURES

- High voltage
- Electrically isolated base plate
- 3000 V_{RMS} isolating voltage
- Industrial standard package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996 
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level



RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	250 A to 320 A
Type	Modules - Diode, High Voltage

DESCRIPTION

This new VSK series of MAGN-A-PAKs uses high voltage power diodes in two basic configurations. The semiconductors are electrically isolated from the metal base, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges and the single diode module can be used in conjunction with the thyristor modules as a freewheel diode. These modules are intended for general purpose applications such as battery chargers, welders and plating equipment and where high voltage and high current are required (motor drives, etc.).

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VSK.250..	VSK.270..	VSK.320..	UNITS
$I_{F(AV)}$		250	270	320	A
	T_C	100	100	100	°C
$I_{F(RMS)}$		393	424	502	A
I_{FSM}	50 Hz	7015	8920	10 110	
	60 Hz	7345	9430	10 580	
I^2t	50 Hz	246	398	511	kA ² s
	60 Hz	225	363	466	
$I^2\sqrt{t}$		2460	3980	5110	kA ² √s
V_{RRM}		400 to 3000			V
T_J		- 40 to 150			°C

VSK.250, VSK.270, VSK.320 Series



Vishay Semiconductors Standard Recovery Diodes, 250 A to 320 A
(MAGN-A-PAK Power Modules)

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT 150 °C mA
VSK.250 VSK.270 VSK.320	04	400	500	50
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
VSK.270	30	3000	3100	

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS	VSK.250	VSK.270	VSK.320	UNITS
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave	250	270	320	A
Maximum RMS forward current	$I_{F(RMS)}$	As AC switch	100	100	100	°C
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	$t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ No voltage reappplied 100 % V_{RRM} reappplied	7015	8920	10 110	A
			7345	9340	10 580	
			5900	7500	8500	
			6180	7850	8900	
Maximum I^2t for fusing	I^2t	$t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ No voltage reappplied 100 % V_{RRM} reappplied	246	398	511	kA ² s
			225	363	466	
			174	281	361	
			159	257	330	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1 \text{ ms to } 10 \text{ ms}$, no voltage reappplied	2460	3980	5110	kA ² √s
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J \text{ maximum}$	0.79	0.74	0.69	V
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$, $T_J = T_J \text{ maximum}$	0.92	0.87	0.86	
Low level forward slope resistance	r_{f1}	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J \text{ maximum}$	0.63	0.94	0.59	mΩ
High level forward slope resistance	r_{f2}	$(I > \pi \times I_{F(AV)})$, $T_J = T_J \text{ maximum}$	0.49	0.81	0.44	
Maximum forward voltage drop	V_{FM}	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = T_J \text{ maximum}$, 180° conduction Average power = $V_{F(TO)} \times I_{F(AV)} + r_f \times (I_{F(RMS)})^2$	1.29	1.48	1.28	V

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse leakage current	I_{RRM}	$T_J = 150 \text{ °C}$	50	mA
RMS insulation voltage	V_{INS}	50 Hz, circuit to base, all terminals shorted, $t = 1 \text{ s}$	3000	V



VSK.250, VSK.270, VSK.320 Series

Standard Recovery Diodes, 250 A to 320 A Vishay Semiconductors
(MAGN-A-PAK Power Modules)

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES			UNITS
				VSK.250	VSK.270	VSK.320	
Maximum junction operating and storage temperature range		T _J , T _{Stg}		- 40 to 150			°C
Maximum thermal resistance, junction to case per junction		R _{thJC}	DC operation	0.16	0.125		K/W
Maximum resistance, case to heatsink per module		R _{thCS}	Mounting surface flat, smooth and greased	0.035			
Mounting torque ± 10 %	MAP to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound.	4 to 6			Nm
	busbar to MAP			8 to 10			
Approximate weight				800			g
				30			oz.
Case style				MAGN-A-PAK			

ΔR CONDUCTION PER JUNCTION											
DEVICE	SINUSOIDAL CONDUCTION AT T _J MAXIMUM					RECTANGULAR CONDUCTION AT T _J MAXIMUM					UNITS
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
VSK.250	0.009	0.010	0.014	0.020	0.032	0.007	0.011	0.015	0.021	0.033	K/W
VSK.270	0.008	0.012	0.014	0.020	0.032	0.007	0.011	0.015	0.020	0.033	
VSK.320	0.008	0.010	0.013	0.020	0.032	0.007	0.011	0.015	0.020	0.033	

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

VSK.250, VSK.270, VSK.320 Series

Vishay Semiconductors Standard Recovery Diodes, 250 A to 320 A
(MAGN-A-PAK Power Modules)

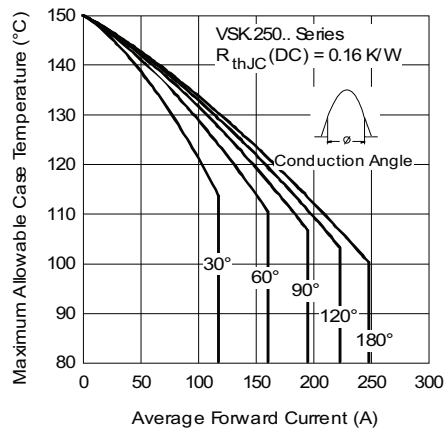


Fig. 1 - Current Ratings Characteristics

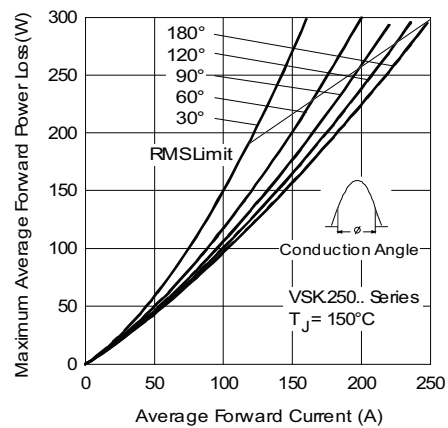


Fig. 3 - Forward Power Loss Characteristics

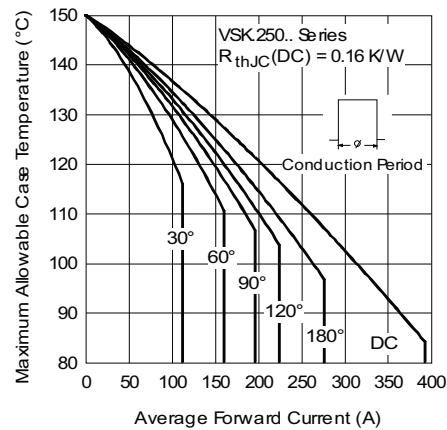


Fig. 2 - Current Ratings Characteristics

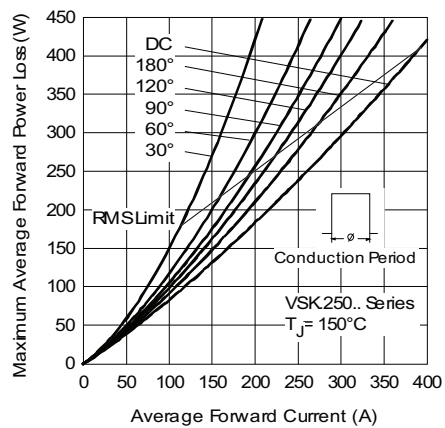


Fig. 4 - Forward Power Loss Characteristics

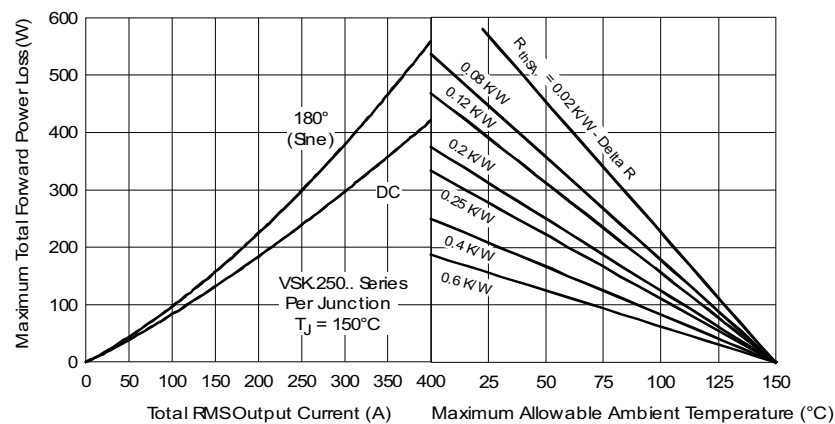


Fig. 5 - Forward Power Loss Characteristics



VSK.250, VSK.270, VSK.320 Series

Standard Recovery Diodes, 250 A to 320 A Vishay Semiconductors
(MAGN-A-PAK Power Modules)

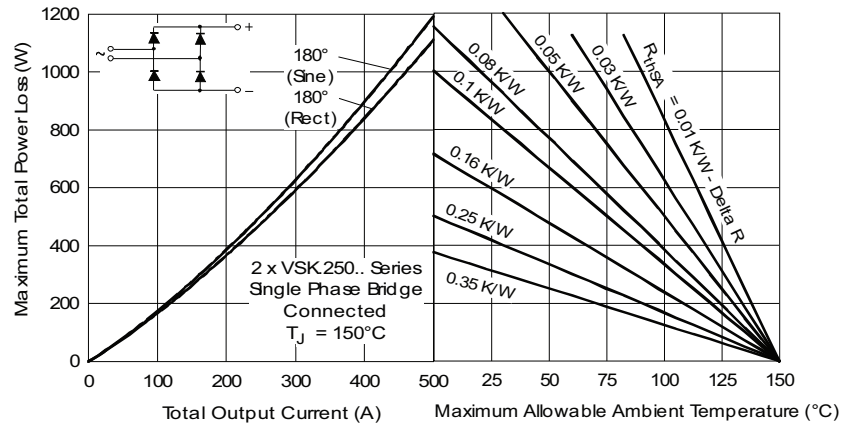


Fig. 6 - Forward Power Loss Characteristics

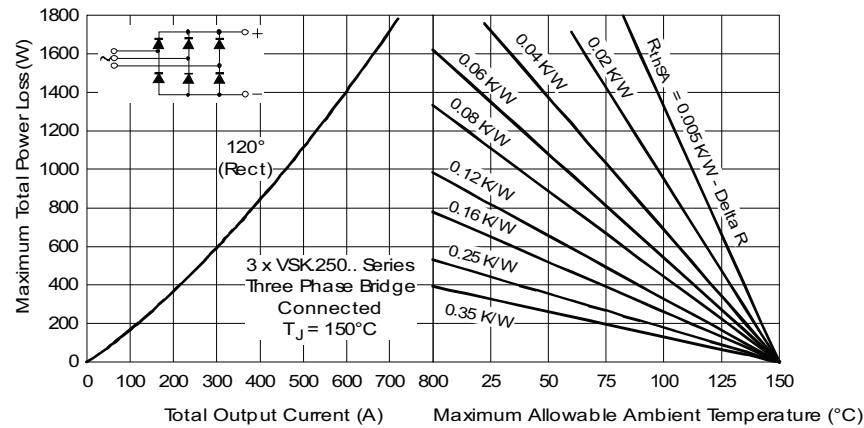


Fig. 7 - Forward Power Loss Characteristics

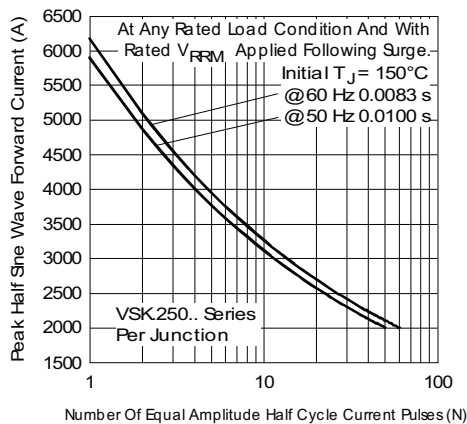


Fig. 8 - Maximum Non-Repetitive Surge Current

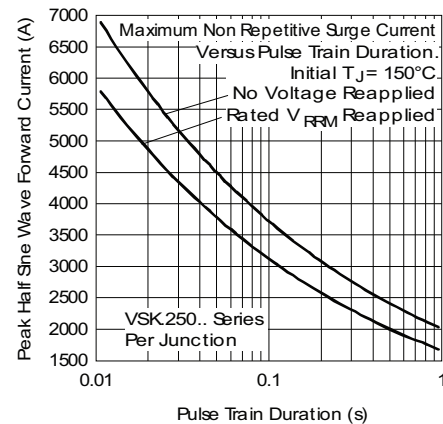


Fig. 9 - Maximum Non-Repetitive Surge Current

VSK.250, VSK.270, VSK.320 Series



Vishay Semiconductors Standard Recovery Diodes, 250 A to 320 A
(MAGN-A-PAK Power Modules)

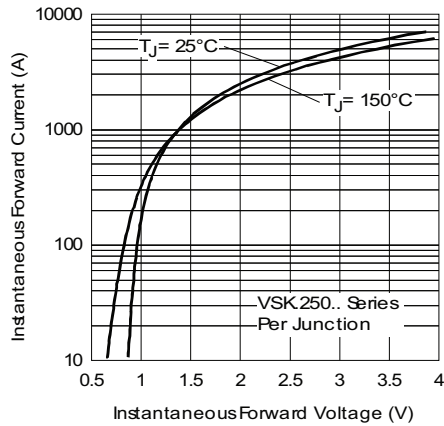


Fig. 10 - Forward Voltage Drop Characteristics

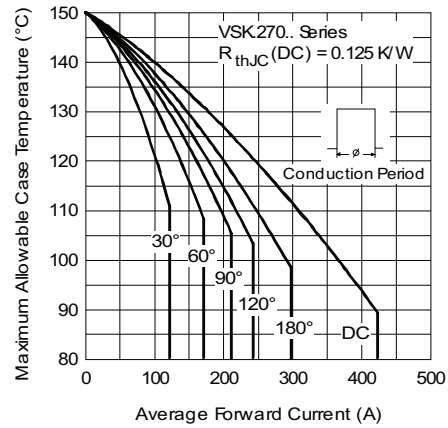


Fig. 13 - Current Ratings Characteristics

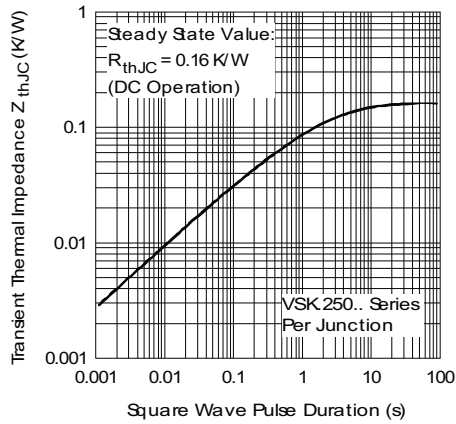


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

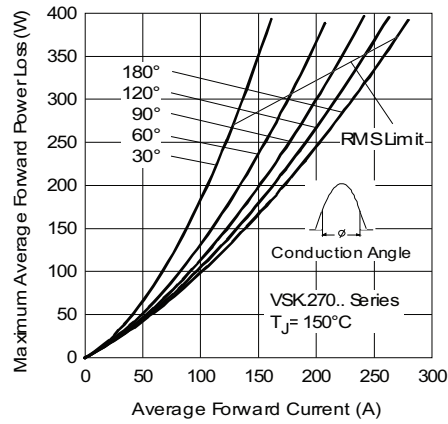


Fig. 14 - Forward Power Loss Characteristics

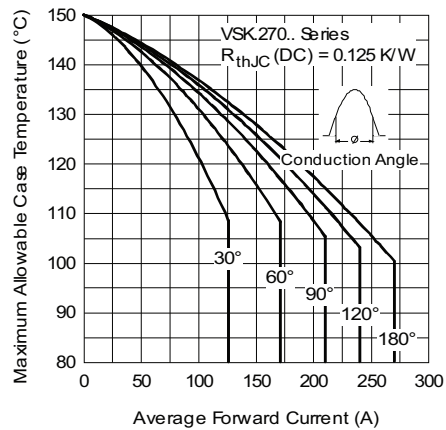


Fig. 12 - Current Ratings Characteristics

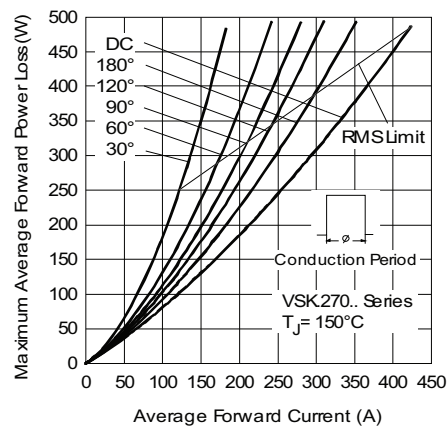


Fig. 15 - Forward Power Loss Characteristics



VSK.250, VSK.270, VSK.320 Series

Standard Recovery Diodes, 250 A to 320 A Vishay Semiconductors
(MAGN-A-PAK Power Modules)

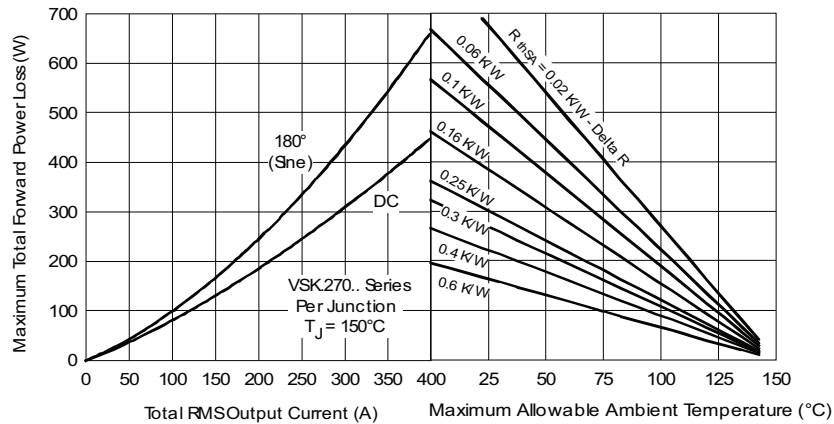


Fig. 16 - Forward Power Loss Characteristics

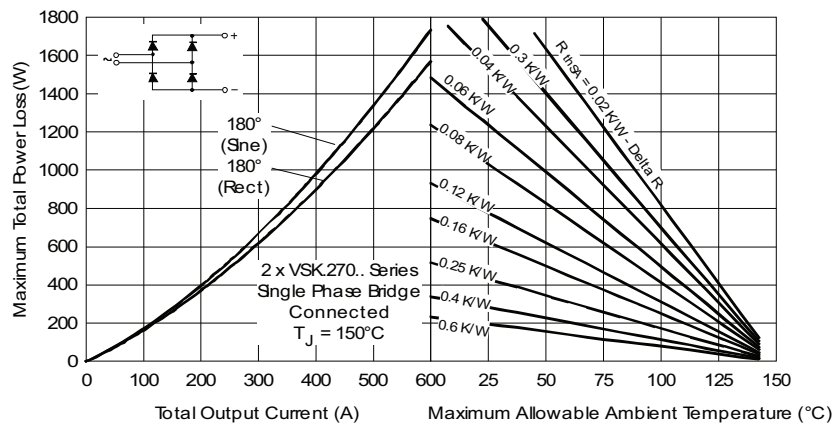


Fig. 17 - Forward Power Loss Characteristics

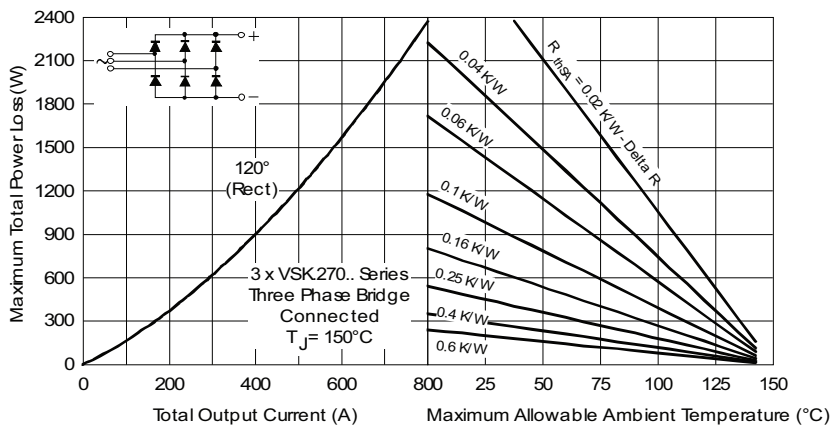


Fig. 18 - Forward Power Loss Characteristics

VSK.250, VSK.270, VSK.320 Series

Vishay Semiconductors Standard Recovery Diodes, 250 A to 320 A
(MAGN-A-PAK Power Modules)

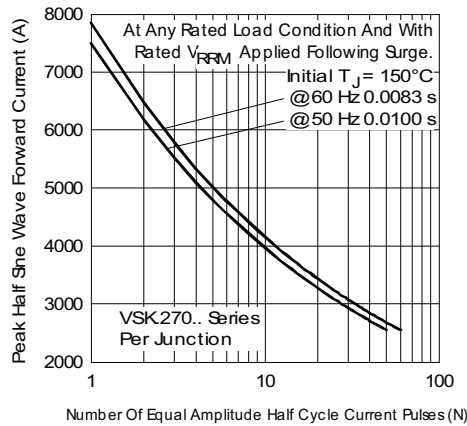


Fig. 19 - Maximum Non-Repetitive Surge Current

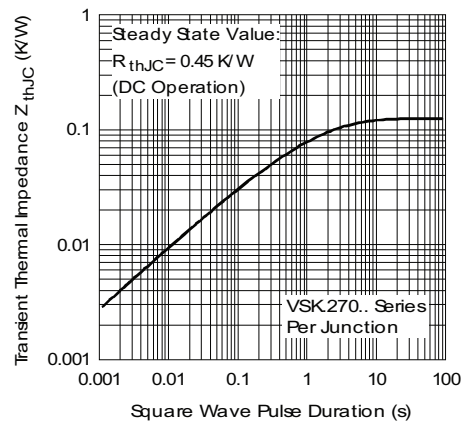


Fig. 22 - Thermal Impedance Z_{thJC} Characteristics

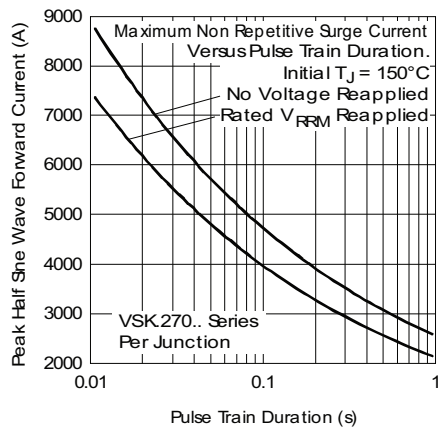


Fig. 20 - Maximum Non-Repetitive Surge Current

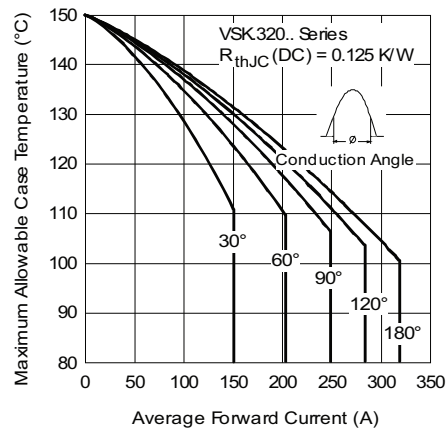


Fig. 23 - Current Ratings Characteristics

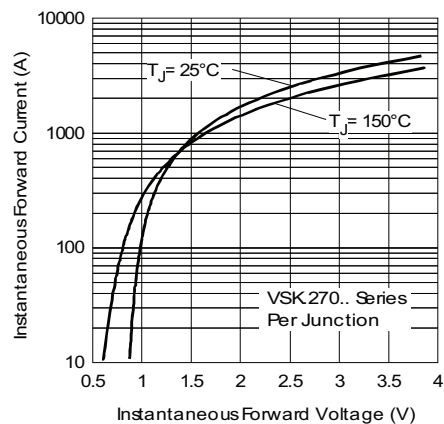


Fig. 21 - Forward Voltage Drop Characteristics

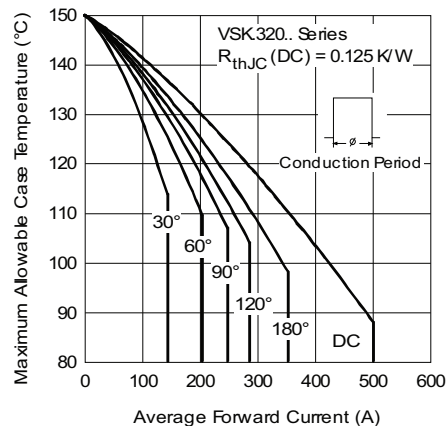


Fig. 24 - Current Ratings Characteristics



VSK.250, VSK.270, VSK.320 Series

Standard Recovery Diodes, 250 A to 320 A Vishay Semiconductors
(MAGN-A-PAK Power Modules)

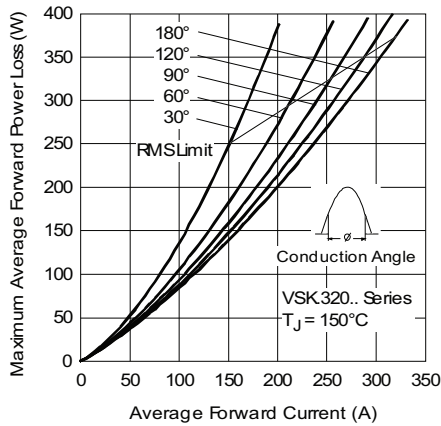


Fig. 25 - Forward Power Loss Characteristics

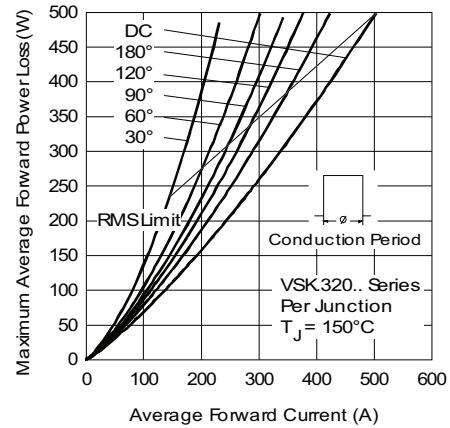


Fig. 26 - Forward Power Loss Characteristics

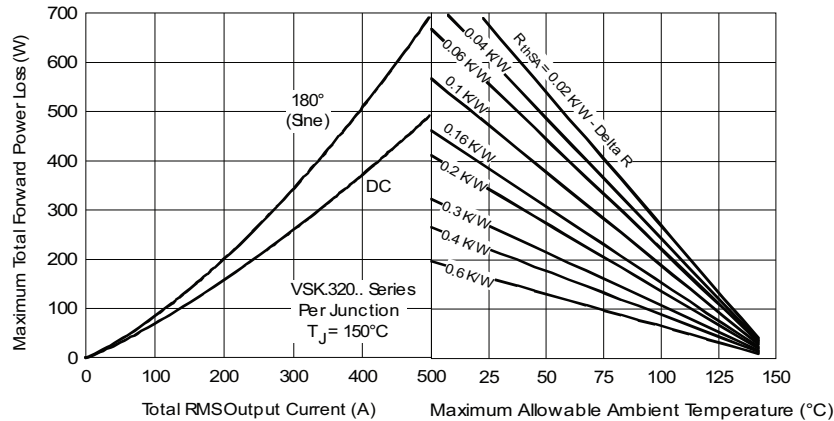


Fig. 27 - Forward Power Loss Characteristics

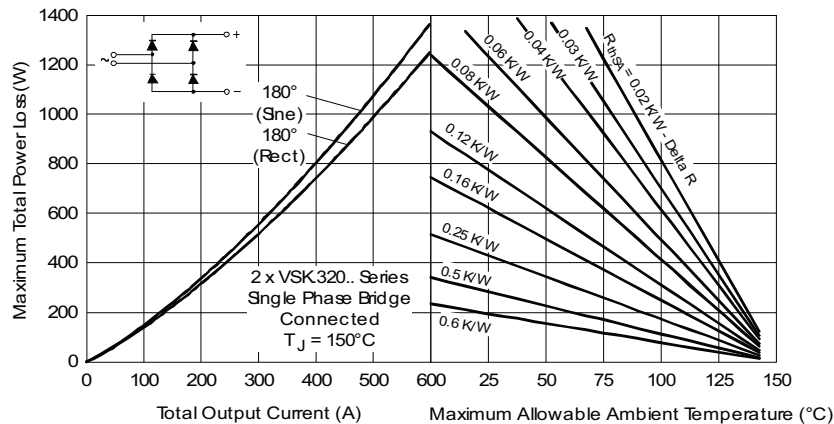


Fig. 28 - Forward Power Loss Characteristics

VSK.250, VSK.270, VSK.320 Series

Vishay Semiconductors Standard Recovery Diodes, 250 A to 320 A
(MAGN-A-PAK Power Modules)

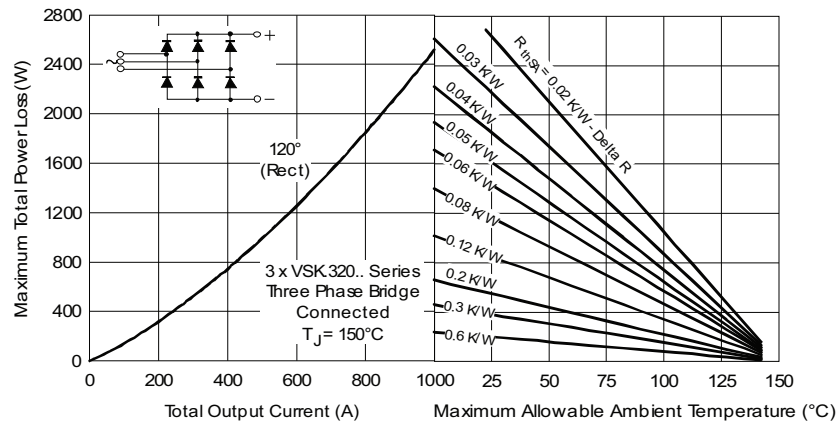


Fig. 29 - Forward Power Loss Characteristics

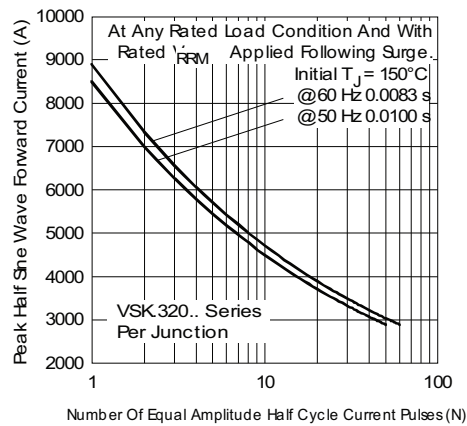


Fig. 30 - Maximum Non-Repetitive Surge Current

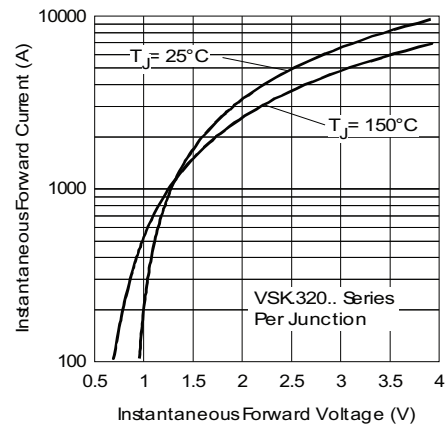


Fig. 32 - Forward Voltage Drop Characteristics

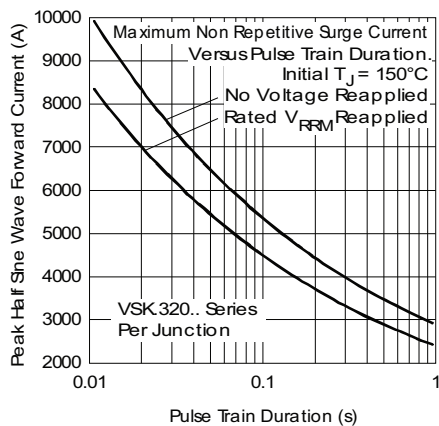


Fig. 31 - Maximum Non-Repetitive Surge Current

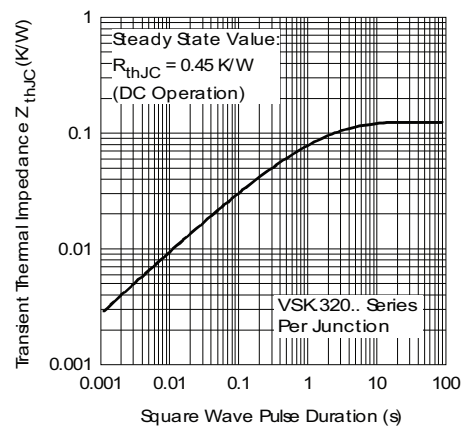


Fig. 33 - Thermal Impedance Z_{thJC} Characteristics



VSK.250, VSK.270, VSK.320 Series

Standard Recovery Diodes, 250 A to 320 A Vishay Semiconductors
(MAGN-A-PAK Power Modules)

ORDERING INFORMATION TABLE

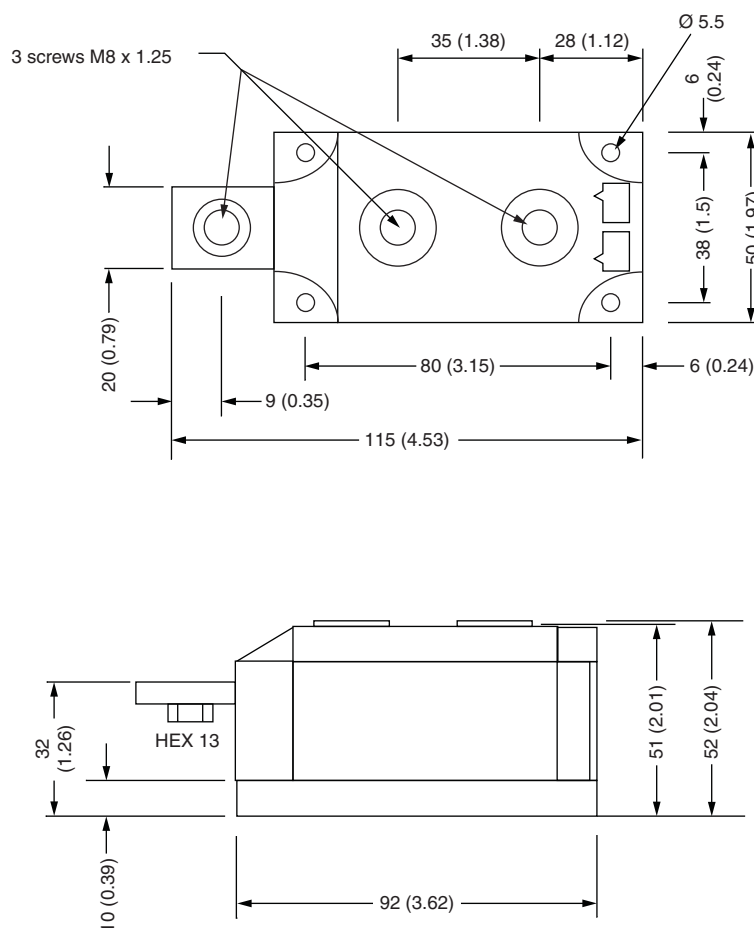
Device code	VSK	D	320	-	24
	①	②	③		④
①	- Module type				
②	- Circuit configuration (see Circuit Configuration table)				
③	- Current rating: $I_{F(AV)}$ rounded				
④	- Voltage code x 100 = V_{RRM} (see Voltage Ratings table)				

CIRCUIT CONFIGURATION		
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Two diodes doubler circuit	D	VSKD...
Two diodes common cathodes	C	VSKC...
Two diodes common anodes	J	VSKJ...
Single diode	E	VSKE...

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95086

MAGN-A-PAK

DIMENSIONS in millimeters (inches)



Notes

- Dimensions are nominal
- Full engineering drawings are available on request
- UL identification number for gate and cathode wire: UL 1385
- UL identification number for package: UL 94 V-0



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.